

Fast CMOS 16-Bit Octal Buffer/Line Drivers

Product Features:

- Supports Mixed Signal Mode Operation
 - 5 Volt Input.
 - 5 Volt Output (when connected to a 5 Volt Bus).
 - Can serve as a 5 volt to 3 volt translator.
- Advanced Low Power CMOS Operation.
- Low Standby Current (Low power CMOS, not Bi-CMOS, so output drive transistors do not require bipolar standby current levels). Typical standby power 1 mW.
- Excellent output drive capability: Balanced drives (24 mA sink and source). Compatible with LVC™ class of products.
- Pin and functional compatible: Industry standard double-density pinouts.
- Low ground bounce outputs, hysteresis on all inputs.
- ESD Protection exceeds 2000 volts.
- Packaged in 48-pin plastic TSSOP and SSOP

Product Description:

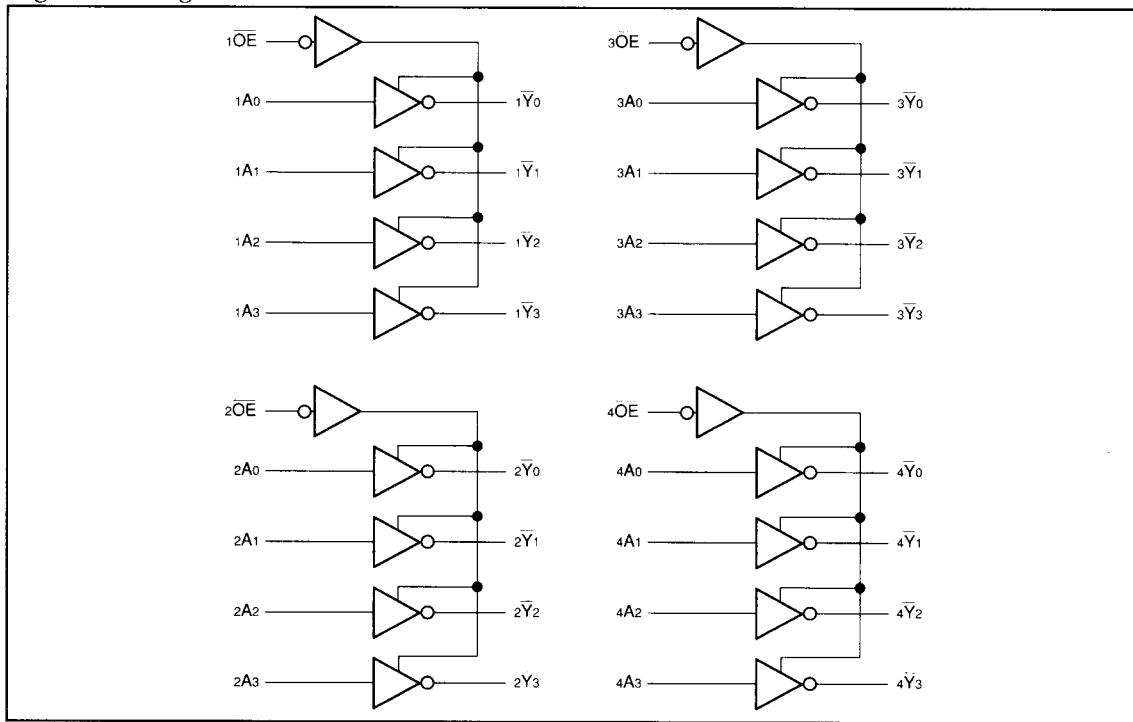
Pericom Semiconductor's PI74FCT series of logic circuits are produced in the Company's advanced 0.8 micron CMOS technology, achieving industry leading speed grades.

The PI74FCT163240 is inverting 16-bit buffer/line drivers designed for applications driving high capacitance loads and low impedance backplanes. These high-speed, low power devices offer bus/backplane interface capability and a flow-through organization for ease of board layout. These devices are designed with three-state controls to operate in a Quad-Nibble, Dual-Byte, or a single 16-bit word mode.

The PI74FCT163240 can be driven from either 3.3 V or 5.0 V devices allowing this device to be used as a translator in a mixed 3.3/5.0 V system.

All products are available in 48-pin 240 mil wide plastic TSSOP and 300 mil wide plastic SSOP packages.

Logic Block Diagram



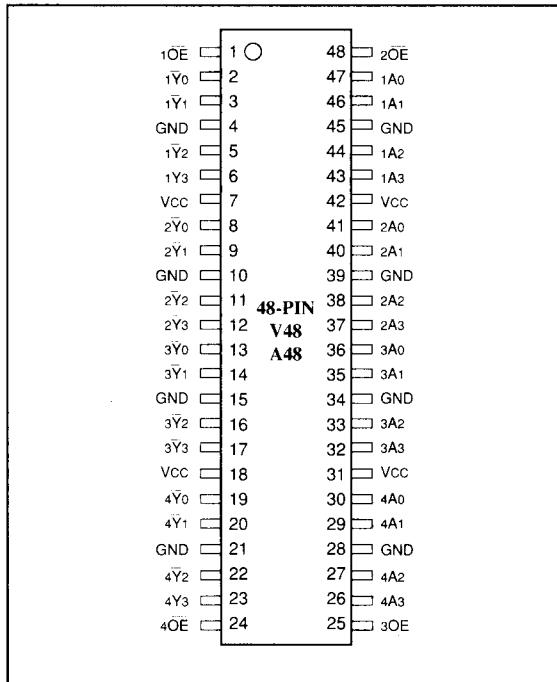
Product Pin Description

Pin Name	Description
xOE	3-State Output Enable Inputs (Active LOW)
xAx	Inputs
xYx	3-State Outputs
GND	Ground
VCC	Power

Truth Table

Inputs ⁽¹⁾		Outputs ⁽¹⁾
xOE	xAx	xYx
L	L	H
L	H	L
H	X	Z

NOTE: 1. H = High Voltage Level, X = Don't Care, L = Low Voltage Level, Z = High Impedance

Product Pin Configuration

Capacitance (TA = 25°C, f = 1 MHz)

Parameters ⁽¹⁾	Description	Test Conditions	Typ	Max.	Units
C _{IN}	Input Capacitance	V _{IN} = 0 V	4.5	6	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0 V	5.5	8	pF

Note:

1. This parameter is determined by device characterization but is not production tested.

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	-55°C to +125°C
Ambient Temperature with Power Applied	-40°C to +85°C
Supply Voltage to Ground Potential (Inputs & Vcc Only)	-0.5V to +7.0V
Supply Voltage to Ground Potential (Outputs & D/O Only)	-0.5V to Vcc
DC Input Voltage	-0.5V to +7.0V
DC Output Current	120 mA
Power Dissipation	1.0W

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics (Over the Operating Range, TA = -40°C to +85°C, VCC = 3.3V ± 0.3V)

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ ⁽²⁾	Max.	Units
VIH	Input HIGH Voltage (Input pins)	Guaranteed Logic HIGH Level	2.2	5.5	5.5	V
	Input HIGH Voltage (I/O pins)		2.0	5.5	5.5	V
VIL	Input LOW Voltage (Input and I/O pins)	Guaranteed Logic LOW Level	-0.5	0.8	0.8	V
I _H	Input HIGH Current (Input pins)	V _{CC} = Max.	V _{IN} = 5.5V		±5	µA
	Input HIGH Current (I/O pins)	V _{CC} = Max.	V _{IN} = V _{CC}		15	µA
I _L	Input LOW Current (Input pins)	V _{CC} = Max.	V _{IN} = GND		±5	µA
	Input LOW Current (I/O pins)	V _{CC} = Max.	V _{IN} = GND		15	µA
I _{OZH}	High Impedance Output Current	V _{CC} = Max.	V _{OUT} = V _{CC}		10	µA
I _{OZL}	(3-State Output pins)	V _{CC} = Max.	V _{OUT} = GND		10	µA
V _{IK}	Clamp Diode Voltage	V _{CC} = Min., I _{IN} = -18 mA			-1.2	V
I _{ODH}	Output HIGH Current	V _{CC} = 3.3V, V _{IN} = VIH or VIL, V _O = 1.5V ⁽³⁾	-36		-110	mA
I _{ODL}	Output LOW Current	V _{CC} = 3.3V, V _{IN} = VIH or VIL, V _O = 1.5V ⁽³⁾	50		200	mA
VOH	Output HIGH Voltage	V _{CC} = Min.	I _{OH} = -0.1mA	V _{CC} -0.2		V
		V _{IN} = VIH or VIL	I _{OH} = -8mA	2.4		V
			I _{OH} = -24mA	2.0		V
VOL	Output LOW Voltage	V _{CC} = Min.	I _{OL} = 0.1mA		0.2	V
		V _{IN} = VIH or VIL	I _{OL} = 16mA		0.4	V
			I _{OL} = 24mA		0.5	V
I _{OS}	Short Circuit Current ⁽⁴⁾	V _{CC} = Max. ⁽³⁾ , V _{OUT} = GND	-60	-135	-240	mA
IOFF		V _{CC} = 0V, V _{IN} or V _{OUT} = 4.5V			100	µA
V _H	Input Hysteresis			150		mV
I _{CCL}	Quiescent Power Supply Current	V _{CC} = Max., V _{IN} = GND or V _{CC}			1.5	mA
I _{CCH}						
I _{CCZ}						

Notes:

- For conditions show as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
- Typical values are at V_{CC} = 3.3, +25°C ambient and maximum loading.
- Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
- This parameter is guaranteed but not tested.

Power Supply Characteristics

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ ⁽²⁾	Max.	Units
ΔI_{CC}	Quiescent Power Supply Current	V _{CC} = Max.	V _{IN} = V _{CC} - 0.6 ⁽³⁾	2.0	30	μA
	TTL Inputs HIGH		V _{IN} = 2.4 V ⁽³⁾		70	500
ICC _D	Dynamic Power Supply ⁽⁴⁾	V _{CC} = Max., Outputs Open xOE = GND One Bit Toggling 50% Duty Cycle	V _{IN} = V _{CC} V _{IN} = GND	50	75	μA/MHz
I _C	Total Power Supply Current ⁽⁶⁾	V _{CC} = Max., Outputs Open f _i = 10 MHz 50% Duty Cycle xOE = GND One Bit Toggling	V _{IN} = V _{CC} - 0.6V V _{IN} = GND	0.6	2.3	mA
		V _{CC} = Max., Outputs Open f _i = 2.5 MHz 50% Duty Cycle xOE = GND 16 Bits Toggling	V _{IN} = 2.4 V V _{IN} = GND	0.6	2.5	
			V _{IN} = V _{CC} - 0.6V V _{IN} = GND	2.1	4.7 ⁽⁵⁾	
			V _{IN} = 2.4 V V _{IN} = GND	2.6	8.5 ⁽⁵⁾	

Notes:

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device.
2. Typical values are at V_{CC} = 3.3 V, +25°C ambient.
3. Per TTL driven input (V_{IN} = 3.4 V); all other inputs at V_{CC} or GND.
4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
5. Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.

6. $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$

$$I_C = I_{CC} + \Delta I_{CC} D_{HNT} + I_{CCD} (f_{CP}/2 + f_i N_i)$$

I_{CC} = Quiescent Current (I_{CCL}, I_{CH} and I_{CCZ})

ΔI_{CC} = Power Supply Current for a TTL High Input

D_H = Duty Cycle for TTL Inputs High

N_T = Number of TTL Inputs at D_H

I_{CCD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

f_{CP} = Clock Frequency for Register Devices (Zero for Non-Register Devices)

N_{CP} = Number of Clock Inputs at f_{CP}

f_i = Input Frequency

N_i = Number of Inputs at f_i

All currents are in millamps and all frequencies are in megahertz.

PI74FCT163240 Switching Characteristics over Operating Range

Parameters	Description	Conditions ⁽¹⁾	'163240T		'163240AT		Unit	
			Com.		Com.			
			Min	Max	Min	Max		
tPLH	Propagation Delay xAX to xYx	C _L = 50 pF R _L = 500Ω	1.5	8.0	1.5	4.8	ns	
tpZH	Output Enable Time		1.5	10.0	1.5	6.2	ns	
tpZL	Output Disable Time		1.5	9.5	1.5	5.6	ns	
tsk(o)	Output Skew ⁽³⁾		—	0.5	—	0.5	ns	

Notes:

1. See test circuit and wave forms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.
3. Skew between any two outputs, of the same package, switching in the same direction. This parameter is guaranteed by design.